

Features

- Operation from 3.0V to 40V Input
- Low Standby Current
- Current Limiting
- Output Switch Current to 1.5A
- Output Voltage Adjustable
- Frequency Operation to 100kHz
- Precision 2% Reference
- SOP-8 and PDIP-8 packages
- Lead Free Available (RoHS Compliant)

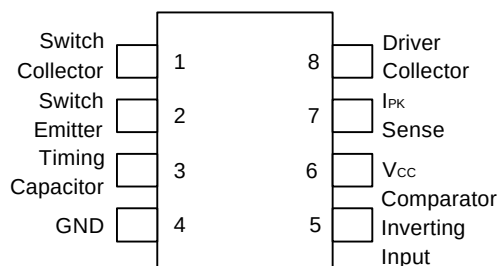
Applications

- DC/DC Converters

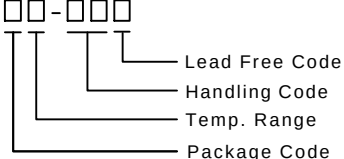
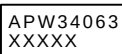
General Description

The APW34063 is a monolithic control circuit containing the primary functions required for DC-to-DC converters. This device consists of an internal temperature compensated reference, comparator, controlled duty cycle oscillator with an active current limit circuit, driver and high current output switch. This device was specifically designed to be incorporated in Step-Down and Step-Up and Voltage-Inverting applications with a minimum number of external components.

Pin Description



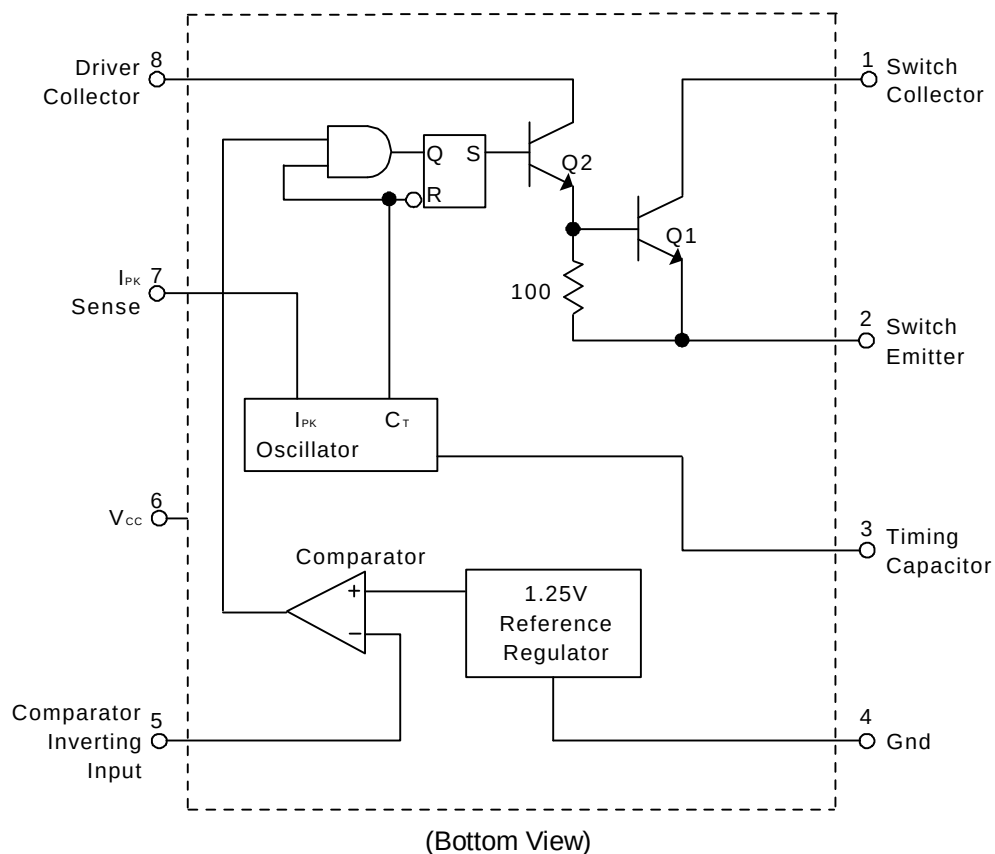
Ordering and Marking Information

APW34063 □□-□□□  Lead Free Code Handling Code Temp. Range Package Code	Package Code J : PDIP - 8 K : SOP-8 Temp. Range C : 0 to 70 °C Handling Code TU : Tube TR : Tape & Reel Lead Free Code L : Lead Free Device Blank : Original Device
APW34063 J : 	XXXXX - Date Code
APW34063 K : 	XXXXX - Date Code

Note: ANPEC lead-free products contain molding compounds/die attach materials and 100% matte in plate termination finish; which are fully compliant with RoHS and compatible with both SnPb and lead-free soldering operations. ANPEC lead-free products meet or exceed the lead-free requirements of IPC/JEDEC J STD-020C for MSL classification at lead-free peak reflow temperature.

ANPEC reserves the right to make changes to improve reliability or manufacturability without notice, and advise customers to obtain the latest version of relevant information to verify before placing orders.

Block Diagram



Absolute Maximum Ratings

Symbol	Parameter	Value	Unit
V_{CC}	Power Supply Voltage	40	Vdc
V_{IR}	Comparator Input Voltage Range	-0.3 to +40	Vdc
$V_{C(Switch)}$	Switch Collector Voltage	40	Vdc
$V_{E(Switch)}$	Switch Emitter Voltage ($V_{PIN1}=40V$)	40	Vdc
$V_{CE(Switch)}$	Switch Collector to Emitter Voltage	40	Vdc
$V_{C(driver)}$	Driver Collector Voltage	40	Vdc
$I_{C(driver)}$	Driver Collector Current (Note1)	100	mA
I_{SW}	Switch Current	1.5	A
P_D	Power Dissipation	PDIP-8 SOP-8 1.25 625	W mW

Note :

1. Maximum package power dissipation limits must be observed.

Absolute Maximum Ratings (Cont.)

Symbol	Parameter	Value	Unit
T_J	Operating Junction Temperature	+150	°C
T_A	Operating Ambient Temperature Range	0 to +70	°C
T_{Stg}	Storage Temperature Range	-65 to +150	°C

Thermal Characteristics

Symbol	Parameter	Value	Unit
$R_{\theta JA}$	Thermal Resistance – Junction to Ambient PDIP-8 SOP-8	100 160	°C/W

Electrical Characteristics

$V_{CC}=5.0V$, $T_A=T_{low}$ to $T_{high}^{(Note2)}$, unless otherwise specified.

Symbol	Parameter	Test Conditions	APW34063			Unit
			Min.	Typ.	Max.	
Oscillator						
F _{OSC}	Frequency	V _{PIN5} =0V, C _T =1.0nF, T _A =25°C	24	33	42	kHz
I _{chg}	Charge Current	V _{CC} =5.0V to 40V, T _A =25°C	24	35	42	μA
I _{dischg}	Discharge Current	V _{CC} =5.0V to 40V, T _A =25°C	140	220	260	μA
I _{dischg} /I _{chg}	Discharge to Charge Current Ratio	Pin7 to V _{CC} , T _A =25°C	5.2	6.5	7.5	
V _{ipk(sense)}	Current Limit Sense Voltage	I _{chg} = I _{dischg} , T _A =25°C	250	300	350	mV
Output Switch ^(Note3)						
V _{CE(sat)}	Saturation Voltage, Darlington Connection	I _{SW} =1.0A, Pins 1,8 connected		1.0	1.3	V
	Saturation Voltage ^(Note4)	I _{SW} =1.0A, R _{PIN8} =82Ω to V _{CC} , Forced β=20		0.45	0.7	
h _{FE}	DC Current Gain	I _{SW} =1.0A, V _{CE} =5.0V, T _A =25°C	50	75		
I _{C(off)}	Collector Off-State Current	V _{CE} =40V		0.01	100	μA
Comparator						
V _{TH}	Threshold Voltage	T _A =25°C	1.225	1.25	1.275	V
		T _A =T _{low} to T _{high}	1.21		1.29	
Reg _{line}	Threshold Voltage Line Regulation	V _{CC} =3.0V to 40V		1.4	5.0	mV
I _B	Input bias Current	V _{IN} =0V		-20	-400	nA
Total Device						
I _{CC}	Supply Current	V _{CC} =5.0V to 40V, C _T =1.0nF, Pin7= V _{CC} , V _{pin5} > V _{IN} , Pin2=Gnd, remaining pins open			4.0	mA

Electrical Characteristics (Cont.)

Note :

2. $T_{low}=0^{\circ}C$, $T_{high}=+70^{\circ}C$

3. Low duty cycle pulse techniques are used during test to maintain junction temperature as close to ambient temperature as possible.

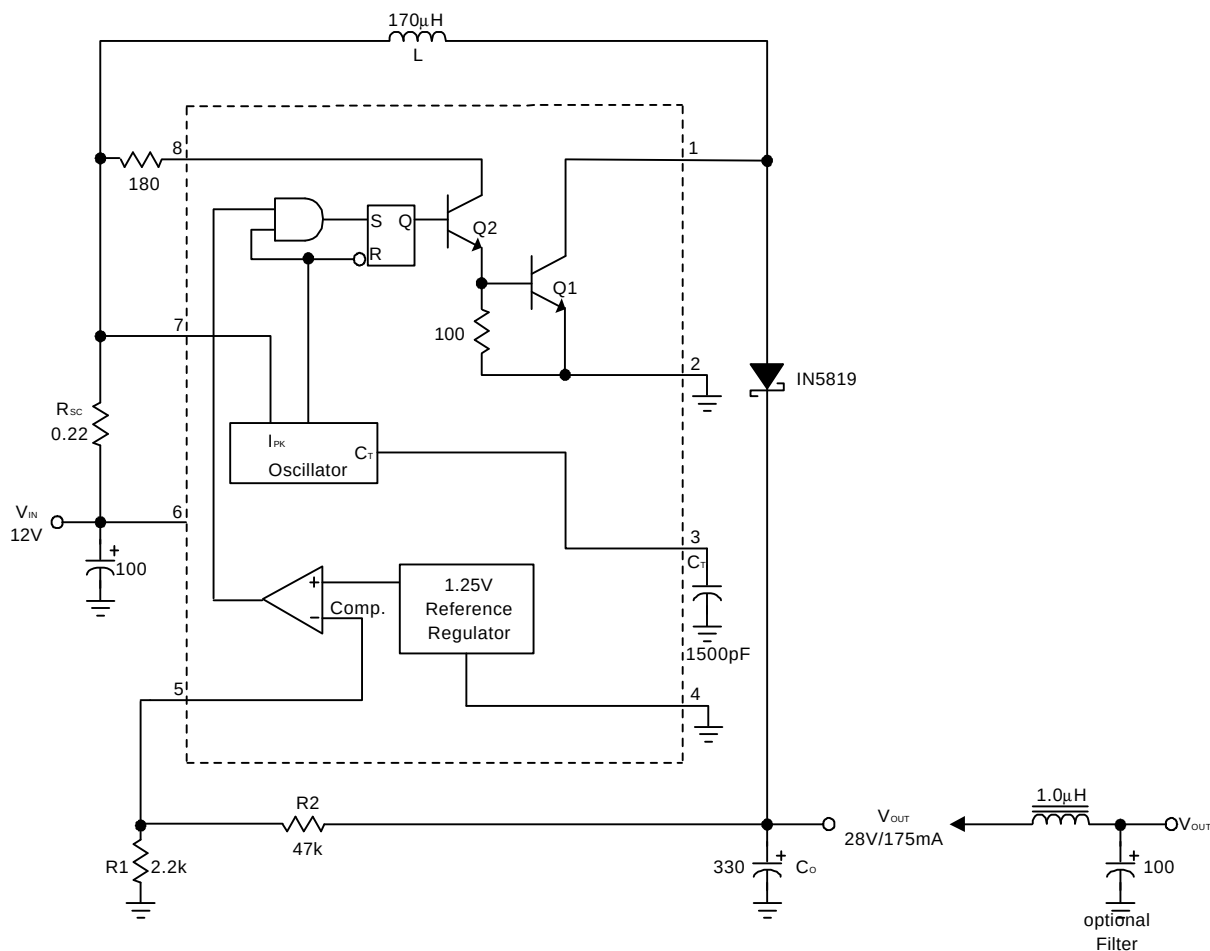
4. If the output switch is driven into hard saturation (non-Darlington configuration) at low switch currents ($\leq 300mA$) and high driver currents ($\geq 30mA$), it may take up to $2.0\mu s$ for it to come out of saturation. This condition will shorten the off time at frequencies $\geq 30kHz$, and is magnified at high temperatures. This condition does not occur with a Darlington configuration, since the output switch cannot saturate. If a non-Darlington configuration is used, the following output drive condition is recommended :

$$\text{Forced } \beta \text{ of output switch : } \frac{I_{c \text{ output}}}{I_{c \text{ driver}} - 7.0mA} \geq 10$$

* The 100Ω resistor in the emitter of the driver device requires about $7.0mA$ before the output switch conducts.

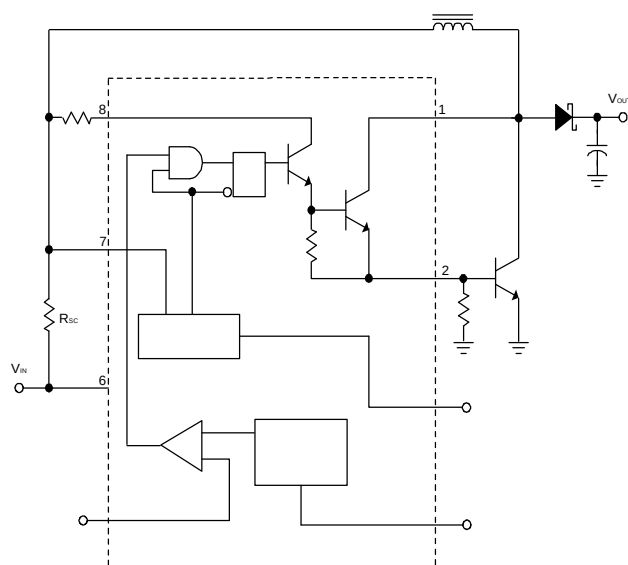
Typical Application Circuits

Step-Up Converter

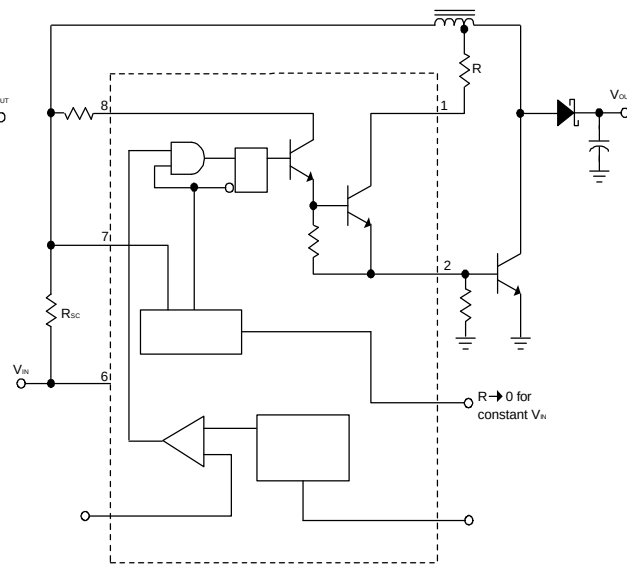


Typical Application Circuits (Cont.)

External Current Boost Connections for I_c Peak Greater than 1.5A



External NPN Switch



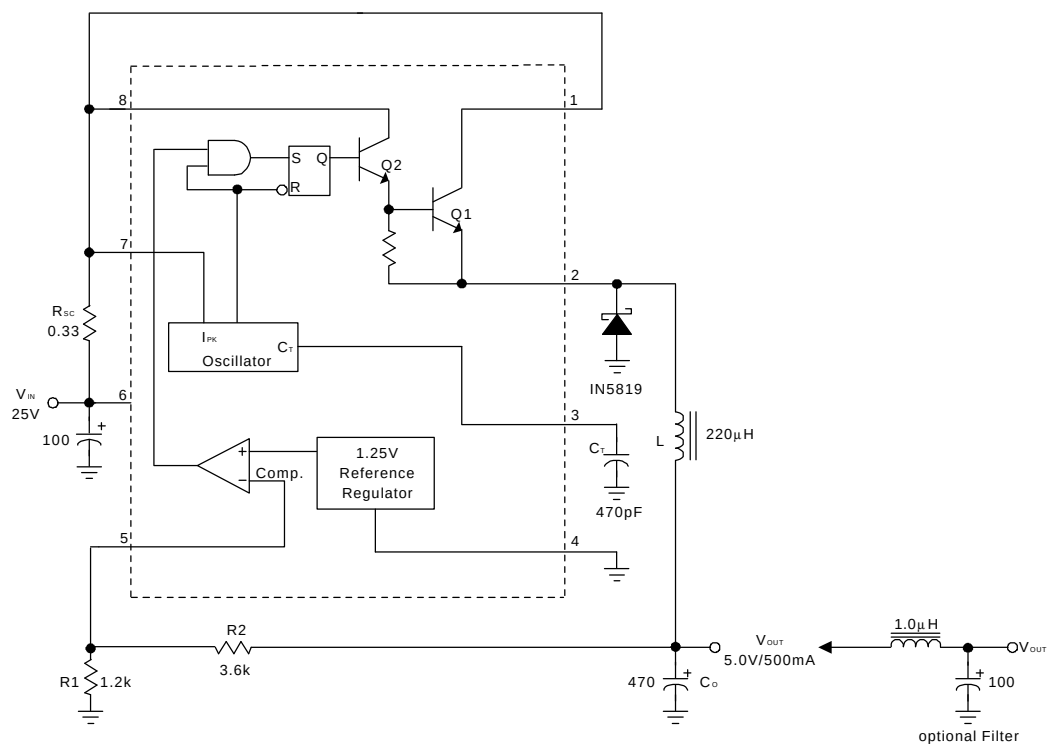
External NPN Saturated Switch (see Note5)

Note :

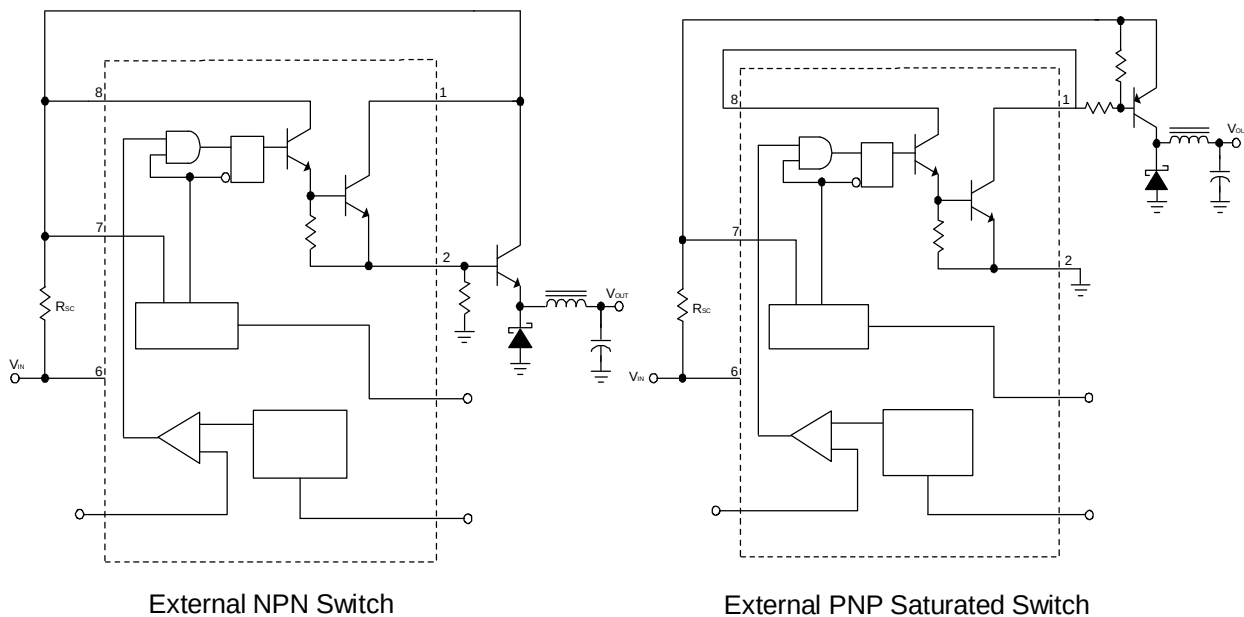
5.If the output switch is driven into hard saturation (non-Darlington configuration) at low switch currents ($\leq 300\text{mA}$) and high driver currents ($\geq 30\text{mA}$), it may take up to $2.0\mu\text{s}$ to come out of saturation. This condition will shorten the off time at frequencies $\geq 30\text{kHz}$, and is magnified at high temperatures. This condition does not occur with a Darlington configuration, since the output switch cannot saturate. If a non-Darlington configuration is used, the following output drive condition is recommended.

Typical Application Circuits (Cont.)

Step-Down Converter

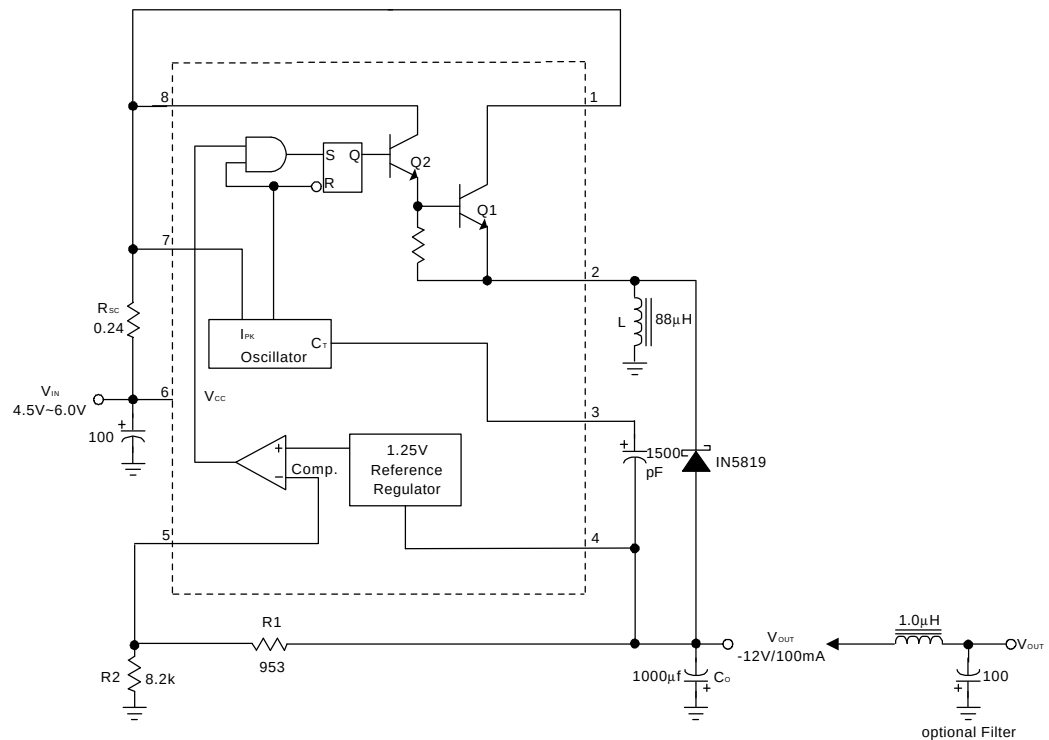


External Current Boost Connections for I_C Peak Greater than 1.5A

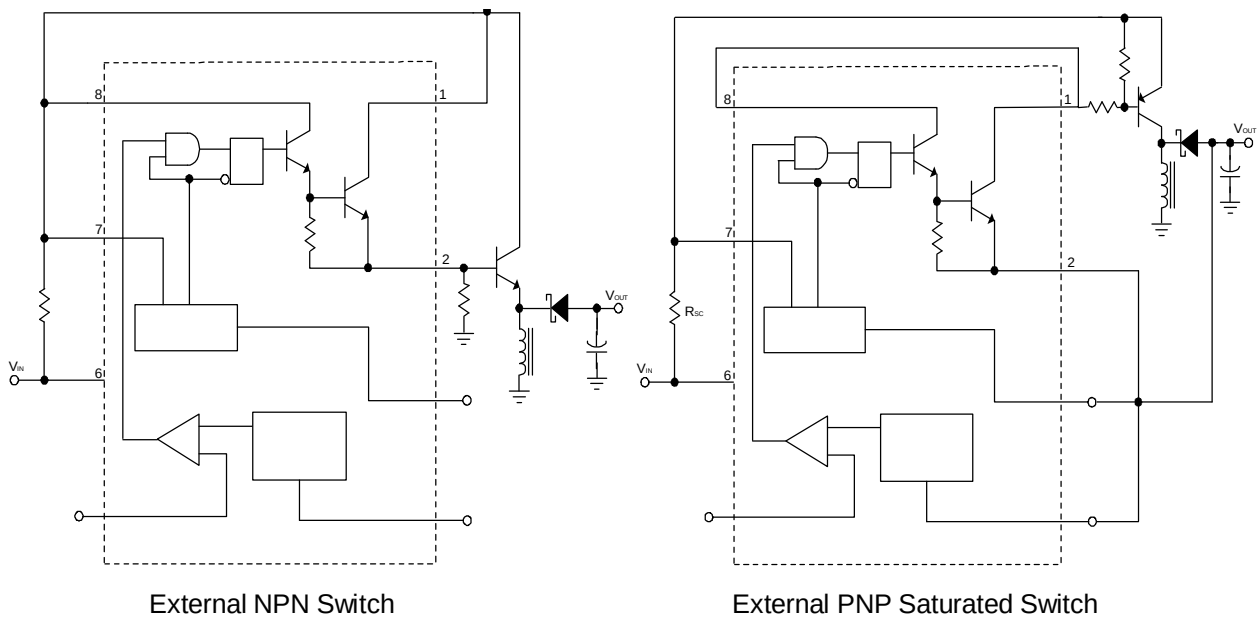


Typical Application Circuits (Cont.)

Voltage Inverting Converter



External Current Boost Connections for I_C Peak Greater than 1.5A



Design Formula Table

Calculation	Set-Up	Step-Down	Voltage-Inverting
t_{on} / t_{off}	$\frac{V_{out} + V_F - V_{in(min)}}{V_{in(min)} - V_{sat}}$	$\frac{V_{out} + V_F}{V_{in(min)} - V_{sat} - V_{out}}$	$\frac{ V_{out} + V_F}{V_{in} - V_{sat}}$
$t_{on} + t_{off}$	$\frac{1}{f}$	$\frac{1}{f}$	$\frac{1}{f}$
t_{off}	$\frac{t_{on} + t_{off}}{\frac{t_{on}}{t_{off}} + 1}$	$\frac{t_{on} + t_{off}}{\frac{t_{on}}{t_{off}} + 1}$	$\frac{t_{on} + t_{off}}{\frac{t_{on}}{t_{off}} + 1}$
t_{on}	$(t_{on} + t_{off}) - t_{off}$	$(t_{on} + t_{off}) - t_{off}$	$(t_{on} + t_{off}) - t_{off}$
C_T	$4.0 \times 10^{-5} t_{on}$	$4.0 \times 10^{-5} t_{on}$	$4.0 \times 10^{-5} t_{on}$
$I_{pk(switch)}$	$2I_{out(max)} \left(\frac{t_{on}}{t_{off}} + 1 \right)$	$2I_{out(max)}$	$2I_{out(max)} \left(\frac{t_{on}}{t_{off}} + 1 \right)$
R_{sc}	$0.3 / I_{pk(switch)}$	$0.3 / I_{pk(switch)}$	$0.3 / I_{pk(switch)}$
$L_{(min)}$	$\left(\frac{V_{in(min)} - V_{sat}}{I_{pk(switch)}} \right) t_{on(max)}$	$\left(\frac{V_{in(min)} - V_{sat} - V_{out}}{I_{pk(switch)}} \right) t_{on(max)}$	$\left(\frac{V_{in(min)} - V_{sat}}{I_{pk(switch)}} \right) t_{on(max)}$
C_o	$9 \frac{I_{out} t_{on}}{V_{ripple(pp)}}$	$\frac{I_{pk(switch)}(t_{on} + t_{off})}{8V_{ripple(pp)}}$	$9 \frac{I_{out} t_{on}}{V_{ripple(pp)}}$

V_{sat} = Saturation voltage of the output switch.

V_F = Forward voltage drop of the output rectifier.

The following power supply characteristics must be chosen :

V_{in} - Nominal input voltage.

V_{out} - Desired output voltage, $I_{V_{out}} = 1.25 \left(1 + \frac{R_2}{R_1} \right)$

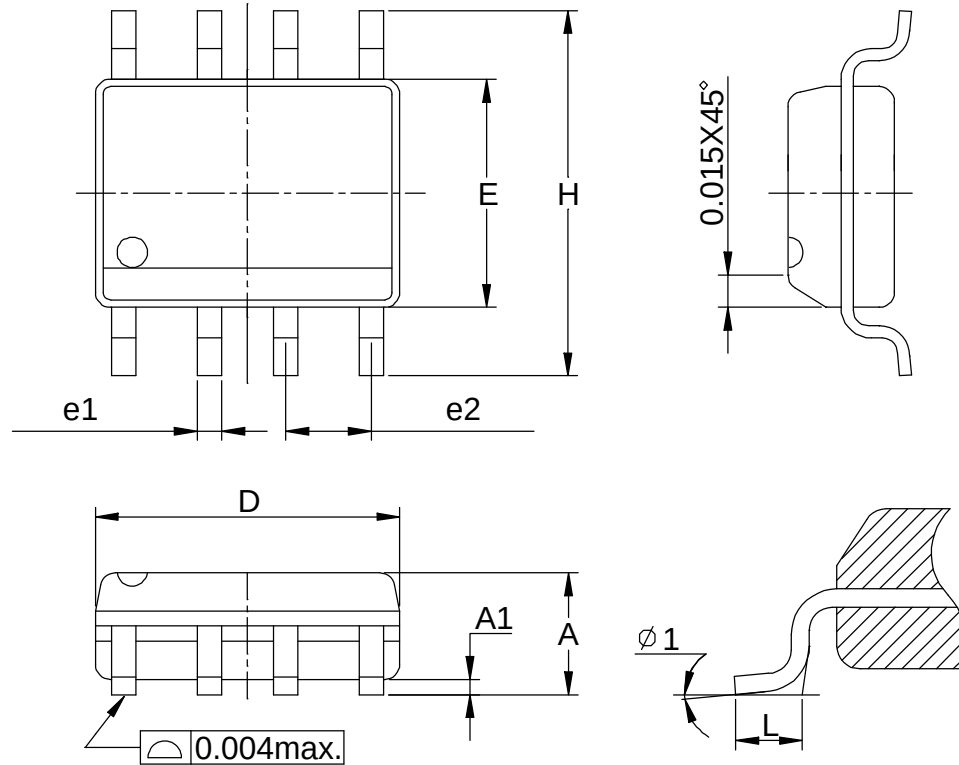
I_{out} - Desired output current.

f_{min} - Minimum desired output switching frequency at the selected values of V_{in} and I_o .

$V_{ripple(pp)}$ - Desired peak-to-peak output ripple voltage. In practice, the calculated capacitor value will need to be increased due to its equivalent series resistance and board layout. The ripple voltage should be kept to a low value since it will directly affect the line and load regulation.

Packaging Information

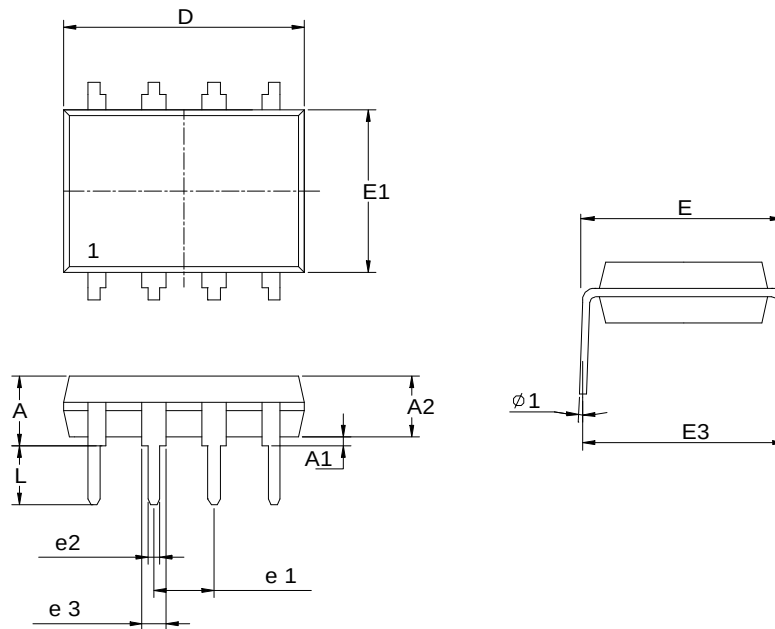
SOP-8 pin (Reference JEDEC Registration MS-012)



Dim	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	1.35	1.75	0.053	0.069
A1	0.10	0.25	0.004	0.010
D	4.80	5.00	0.189	0.197
E	3.80	4.00	0.150	0.157
H	5.80	6.20	0.228	0.244
L	0.40	1.27	0.016	0.050
e1	0.33	0.51	0.013	0.020
e2	1.27BSC		0.50BSC	
$\phi 1$	8°		8°	

Packaging Information

PDIP-8 pin (Reference JEDEC Registration MS-001)

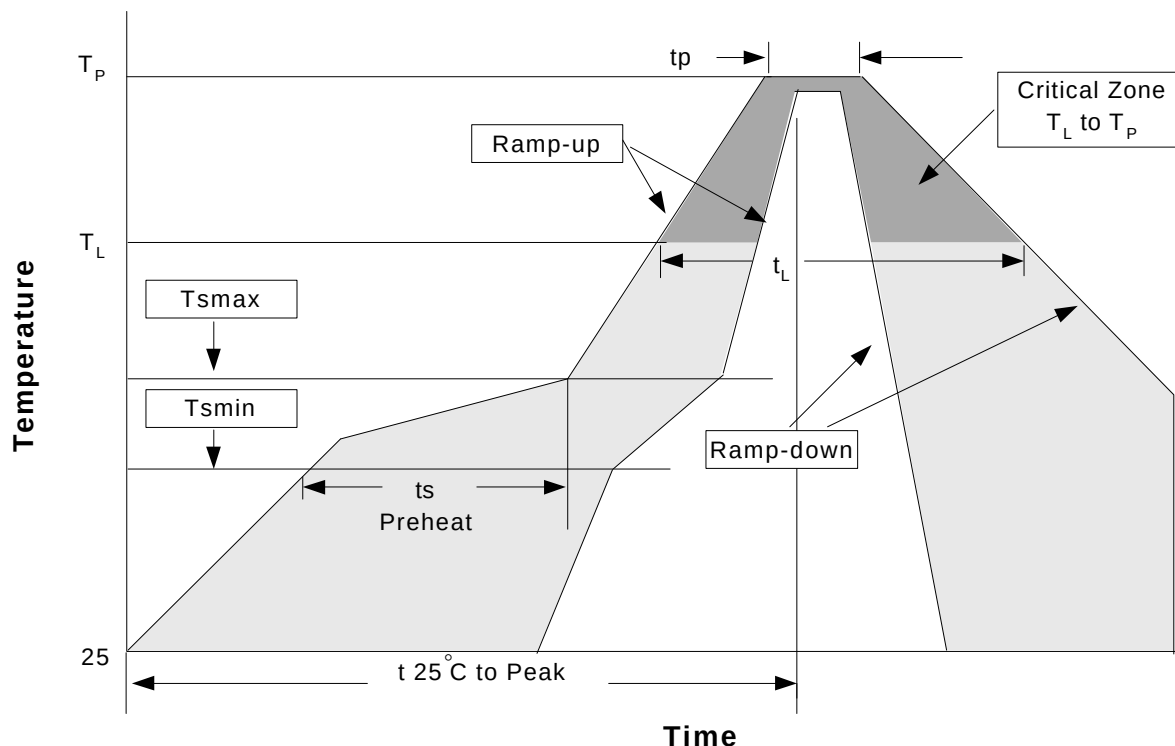


Dim	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A		5.33		0.210
A1	0.38		0.015	
A2	2.92	3.68	0.115	0.145
D	9.02	10.16	0.355	0.400
e1	2.54BSC		0.100BSC	
e2	0.36	0.56	0.014	0.022
e3	1.14	1.78	0.045	0.070
E	7.62 BSC		0.300 BSC	
E1	6.10	7.11	0.240	0.280
E3		10.92		0.430
L	2.92	3.81	0.115	0.150
φ 1	15°		15°	

Physical Specifications

Terminal Material	Solder-Plated Copper (Solder Material : 90/10 or 63/37 SnPb), 100%Sn
Lead Solderability	Meets EIA Specification RSI86-91, ANSI/J-STD-002 Category 3.

Reflow Condition (IR/Convection or VPR Reflow)



Classification Reflow Profiles

Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Average ramp-up rate (T _L to T _P)	3°C/second max.	3°C/second max.
Preheat		
- Temperature Min (T _{min})	100°C	150°C
- Temperature Max (T _{max})	150°C	200°C
- Time (min to max) (ts)	60-120 seconds	60-180 seconds
Time maintained above:		
- Temperature (T _L)	183°C	217°C
- Time (t _L)	60-150 seconds	60-150 seconds
Peak/Classification Temperature (Tp)	See table 1	See table 2
Time within 5°C of actual Peak Temperature (tp)	10-30 seconds	20-40 seconds
Ramp-down Rate	6°C/second max.	6°C/second max.
Time 25°C to Peak Temperature	6 minutes max.	8 minutes max.

Notes: All temperatures refer to topside of the package .Measured on the body surface.

(mm)

Classification Reflow Profiles(Cont.)

Table 1. SnPb Eutectic Process – Package Peak Reflow Temperatures

Package Thickness	Volume mm ³ <350	Volume mm ³ ≥ 350
<2.5 mm	240 +0/-5°C	225 +0/-5°C
≥2.5 mm	225 +0/-5°C	225 +0/-5°C

Table 2. Pb-free Process – Package Classification Reflow Temperatures

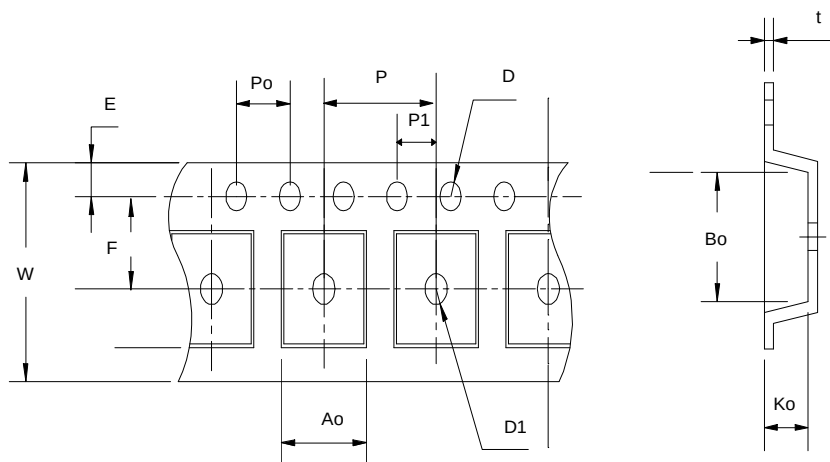
Package Thickness	Volume mm ³ <350	Volume mm ³ 350-2000	Volume mm ³ >2000
<1.6 mm	260 +0°C*	260 +0°C*	260 +0°C*
1.6 mm – 2.5 mm	260 +0°C*	250 +0°C*	245 +0°C*
≥2.5 mm	250 +0°C*	245 +0°C*	245 +0°C*

*Tolerance: The device manufacturer/supplier **shall** assure process compatibility up to and including the stated classification temperature (this means Peak reflow temperature +0°C. For example 260°C+0°C) at the rated MSL level.

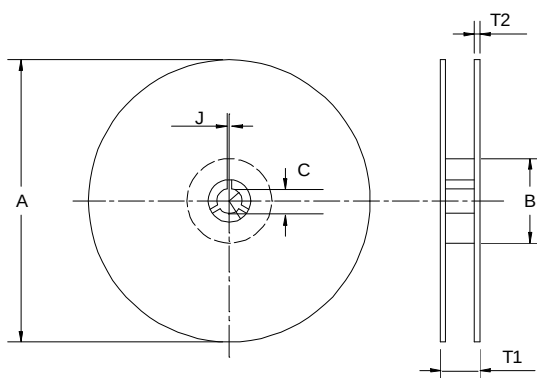
Reliability Test Program

Test item	Method	Description
SOLDERABILITY	MIL-STD-883D-2003	245°C, 5 SEC
HOLT	MIL-STD-883D-1005.7	1000 Hrs Bias @125°C
PCT	JESD-22-B,A102	168 Hrs, 100%RH, 121°C
TST	MIL-STD-883D-1011.9	-65°C~150°C, 200 Cycles
ESD	MIL-STD-883D-3015.7	VHBM > 2KV, VMM > 200V
Latch-Up	JESD 78	10ms, $I_{tr} > 100\text{mA}$

Carrier Tape & Reel Dimensions



Carrier Tape & Reel Dimensions(Cont.)



Application	A	B	C	J	T1	T2	W	P	E
SOP- 8	330 ± 1	$62 +1.5$	$12.75^{+0.15}$	2 ± 0.5	12.4 ± 0.2	2 ± 0.2	12 ± 0.3	8 ± 0.1	1.75 ± 0.1
	F	D	D1	Po	P1	Ao	Bo	Ko	t
	5.5 ± 1	$1.55 +0.1$	$1.55 + 0.25$	4.0 ± 0.1	2.0 ± 0.1	6.4 ± 0.1	5.2 ± 0.1	2.1 ± 0.1	0.3 ± 0.013

(mm)

Cover Tape Dimensions

Application	Carrier Width	Cover Tape Width	Devices Per Reel
SOP- 8	12	9.3	2500

Customer Service

Anpec Electronics Corp.

Head Office :

5F, No. 2 Li-Hsin Road, SBIP,

Hsin-Chu, Taiwan, R.O.C.

Tel : 886-3-5642000

Fax : 886-3-5642050

Taipei Branch :

7F, No. 137, Lane 235, Pac Chiao Rd.,

Hsin Tien City, Taipei Hsien, Taiwan, R. O. C.

Tel : 886-2-89191368

Fax : 886-2-89191369